International INPR Rectifier

IR04H420

HIGH VOLTAGE HALF-BRIDGE

Features

- Output Power MOSFETs in half-bridge configuration
- 500V Rated Breakdown Voltage
- High side gate drive designed for bootstrap operation
- Matched propagation delay for both channels
- Independent high and low side output channels
- Undervoltage lockout
- 5V Schmitt-triggered input logic
- Half-Bridge output in phase with IN
- Cross conduction prevention logic
- Internally set dead time
- Shut down input turns off both channels

Description

The IR04H420 is a high voltage, high speed half bridge. Proprietary HVIC and latch immune CMOS technologies, along with the HEXFET[®] power MOSFET technology, enable ruggedized single package construction. The logic inputs are compatible with standard CMOS or LSTTL outputs. The front end features an independent high and low side driver in phase with the logic compatible input signals. The output features two HEXFETs in a half-bridge configuration with a high pulse current buffer stage designed for minimum cross-conduction in the halfbridge. Propagation delays for the high and low side power MOSFETs are matched to simplify use. The device can operate up to 500 volts.

Product Summary

V _{IN} (max)	500V
t _{on/off}	130 ns
t _{rr}	270 ns
R _{DS(on)}	3.0 Ω
P _D (T _A = 25 °C)	2.0W

Package



Typical Connection



Absolute Maximum Ratings

Absolute Maximum Ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM, all currents are defined positive into any lead. The Thermal Resistance and Power Dissipation ratings are measured under board mounted and still air conditions.

	Parameter			
Symbol	Definition	Min.	Max.	Units
VIN	High Voltage Supply	-0.3	500	
VB	High Side Floating Supply Absolute Voltage	-0.3	525	
VO	Half-Bridge Output Voltage	-0.3	V _{IN} + 0.3	V
VIH	Logic Input Voltage (IN & SD)	-0.3	V _{CC} + 0.3	
V _{CC}	Low Side and Logic Fixed Supply Voltage	-0.3	25	
dv/dt	Peak Diode Recovery dv/dt		3.5	V/ns
PD	Package Power Dissipation @ $T_A \le +25^{\circ}C$		2.00	W
R _{θJA}	Thermal Resistance, Junction to Ambient		60	°C/W
TJ	Junction Temperature	-55	150	
Ts	Storage Temperature	-55	150	°C
TL	Lead Temperature (Soldering, 10 seconds)		300	

Recommended Operating Conditions

The Input/Output logic timing diagram is shown in Figure 1. For proper operation the device should be used within the recommended conditions.

	Parameter			
Symbol	Definition	Min.	Max.	Units
VB	High Side Floating Supply Absolute Voltage	VO + 10	VO + 20	
VIN	High Voltage Supply		500	V
VO	Half-Bridge Output Voltage	(note 1)	500	
Vcc	Low Side and Logic Fixed Supply Voltage	10	20	
VIH	Logic Input Voltage (IN & SD)	0	Vcc	
ID	Continuous Drain Current $(T_A = 25^{\circ}C)$		0.7	Α
	(T _A = 85°C)		0.5	
T _A	Ambient Temperature	-40	125	°C

Note 1: Logic operational for VO of -5 to 500 V. Logic state held for VO of -5 to - V_{B} .

Dynamic Electrical Characteristics

 V_{BIAS} (V_{CC}, V_B) = 15V and T_A = 25°C unless otherwise specified. Switching time waveform definitions are shown in figure 2.

	Parameter	T,	_A = 25°	С		
Symbol	Definition	Min.	Тур.	Max.	Units	Test Conditions
t _{on}	Turn-On Propagation Delay (see note 2)		600	720		$V_{S} = 0 V$
t _{off}	Turn-Off Propagation Delay (see note 2)		90	200		V _S = 500 V
tr	Turn-On Rise Time (see note 2)		80	120	ns	
t _f	Turn-Off Fall Time (see note 2)		40	70		
MT	Delay Matching, HS & LS Turn-On/Off		30			
DT	Deadtime, LS Turn-Off to HS Turn-On & HS Turn-On to LS Turn-Off		500	750		
t _{rr}	Reverse Recovery Time (MOSFET Body Diode)		260			I _F = 0.7 A
Q _{rr}	Reverse Recovery Charge (MOSFET Body Diode)		0.7		μC	di/dt = 100A/µs

Note 2: Switching times as specified and illustrated in figure 2 are referenced to the MOSFET gate input voltage. This is shown as HO in figure 2.

Static Electrical Characteristics

 V_{BIAS} (V_{CC}, V_B) = 15V and T_A = 25°C unless otherwise specified. The Input voltage and current levels are referenced to COM.

	Parameter	T	T _A = 25°C		T _A = 25°C		T _A = 25°C			
Symbol	Definition	Min.	Тур.	Max.	Units	Test Conditions				
Supply	Supply Characteristics									
V _{CCUV+}	V _{CC} Supply Undervoltage Positive Going Threshold	8.8	9.3	9.8	V					
V _{CCUV} -	V _{CC} Supply Undervoltage Negative Going Threshold	7.5	8.2	8.6						
lacc	Quiescent V _{CC} Supply Current		140	240						
I _{QBS}	Quiescent V _{BS} Supply Current		20	50	μA					
los	Offset Supply Leakage Current			50		$V_B = V_S = 500V$				
Input Ch	naracteristics									
VIH	Logic "1" Input Voltage	2.7								
VIL	Logic "0" Input Voltage			0.8	V	V_{CC} = 10V to 20V				
$V_{SD.TH+}$	SD Input Positive Going Threshold	2.7								
V _{SD.TH-}	SD Input Negative Going Threshold			0.8						
I _{IN+}	Logic "1" Input Bias Current		20	40	μA					
I _{IN-}	Logic "0" Input Bias Current			1.0	μA					
Output (Output Characteristics									
R _{DS(on)}	Static Drain-to-Source On-Resistance		3.0		Ω	I _D = 700mA				
V_{SD}	Diode Forward Voltage		0.8		V	T _i = 150 °C				

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Functional Block Diagram



Lead Definitions

	Lead			
Symbol	Description			
Vcc	Logic and internal gate drive supply voltage.			
IN	Logic input for high and low side gate driver outputs (HO and LO), in phase with HO			
SD	Logic input for shutdown			
VB	High side gate drive floating supply. For bootstrap operation a high voltage fast recovery diode is needed to feed from V_{CC} to V_B .			
VIN	High voltage supply.			
VO	Half-Bridge output.			
COM	Logic and low side of Half-Bridge return.			

Lead Assignments



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Figure 2. Switching Time Waveform Definitions



Figure 3. Delay Matching Waveform Definitions



Figure 4. Deadtime Waveform Definitions

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Figure 5. Shutdown Waveform Definitions



NOTES:

1. DIMENSIONING & TOLERANCING PER ANSI Y14.5M-1982.

2. CONTROLLING DIMENSION: INCH.

3. DIMENSIONS ARE SHOWN IN MILLIMETERS (INCHES).

Package Outline

International ISPR Rectifier

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Data and specifications subject to change without notice.

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